DECLARATION OF INVENTORSHIP AND POWER OF ATTORNEY FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

and joint inventor (if I which a patent is sough	olural names are it on the invention E SEMICON	e listed below) of the son entitled:	name is listed below) or an original subject matter which is claimed GE AND FABRICATION	inal, firs
The specification of v	which			
(check one)				
	under Applica	ation Serial No.		and was
including the claims, as	amended by an to disclose to	y amendment referred t	nts of the above-identified speci to above. ion which is material to Patenta	
inventor's certificate lis	sted below and l	nave also identified bel	of any foreign application(s) for pow any foreign application for plication on which priority is claim	patent of
Prior Foreign Applica	ation(s)			
APPLICATION	NUMBER	COUNTRY	FILING DATE	

I hereby claim the benefit under 35 USC §120 of any United States application(s) listed below and insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 USC § 112, I acknowledge the duty to disclose to the Office information which is material to patentability as defined in CFR § 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application.

APPLICATION NUMBER FILING DATE

STATUS

(Patented, Pending, Abandoned)

I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith:

Address all correspondence to: ANDERSON KILL & OLICK, P.C.

1251 Avenue of the Americas,

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U.S.A.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 USC 1001, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

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Full name of third joint inventor, if any	Dota			
Residence	Date			
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